

**BC856T SERIES  
BC857T SERIES**

**SURFACE MOUNT  
PNP SILICON TRANSISTOR**

**ULTRAmi<sup>TM</sup>**



**SOT-523 CASE**

# Central<sup>TM</sup>

**Semiconductor Corp.**

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR BC856T and BC857T Series types are PNP Silicon Transistors manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for general purpose switching and amplifier applications.

**MARKING CODE: PLEASE SEE MARKING CODE TABLE ON FOLLOWING PAGE**

**MAXIMUM RATINGS** ( $T_A=25^\circ\text{C}$ )

	SYMBOL	BC857T	BC856T	UNITS
Collector-Base Voltage	$V_{CBO}$	50	80	V
Collector-Emitter Voltage	$V_{CEO}$	45	65	V
Emitter-Base Voltage	$V_{EBO}$		5.0	V
Collector Current	$I_C$		100	mA
Peak Collector Current	$I_{CM}$		200	mA
Peak Base Current	$I_{BM}$		100	mA
Power Dissipation	$P_D$		250	mW
Operating and Storage				
Junction Temperature	$T_J, T_{stg}$		-65 to +150	$^\circ\text{C}$
Thermal Resistance	$\Theta_{JA}$		500	$^\circ\text{C}/\text{W}$

**ELECTRICAL CHARACTERISTICS** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

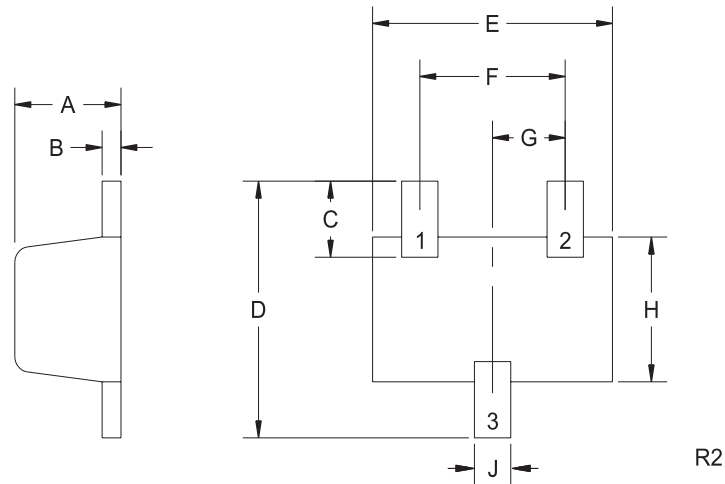
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$I_{CBO}$	$V_{CB}=30\text{V}$			15	nA
$I_{CBO}$	$V_{CB}=30\text{V}, T_A=150^\circ\text{C}$			5.0	$\mu\text{A}$
$I_{EBO}$	$V_{EB}=5.0\text{V}$			100	nA
$BV_{CBO}$	$I_C=10\mu\text{A}$ (BC857T)	50			V
$BV_{CBO}$	$I_C=10\mu\text{A}$ (BC856T)	80			V
$BV_{CEO}$	$I_C=10\text{mA}$ (BC857T)	45			V
$BV_{CEO}$	$I_C=10\text{mA}$ (BC856T)	65			V
$BV_{EBO}$	$I_E=10\mu\text{A}$	5.0			V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$			0.2	V
$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=5.0\text{mA}$			0.4	V
$V_{BE(ON)}$	$I_C=2.0\text{mA}, V_{CE}=5.0\text{V}$	0.58		0.70	V
$V_{BE(ON)}$	$I_C=10\text{mA}, V_{CE}=5.0\text{V}$			0.77	V
$f_T$	$V_{CE}=5.0\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	100			MHz
$C_c$	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$			2.5	pF
$C_e$	$V_{EB}=0.5\text{V}, I_C=0, f=1.0\text{MHz}$		10		pF
NF	$V_{CE}=5.0\text{V}, I_C=200\mu\text{A}, R_S=2\text{K}\Omega, f=1\text{KHz}, BW=200\text{Hz}$			10	dB

	SYMBOL	<u>BC856AT</u>		<u>BC856BT</u>		<u>BC857CT</u>	
		MIN	MAX	MIN	MAX	MIN	MAX
$h_{FE}$	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$	125	250	220	475	420	800

R0 (30-October 2003)

SOT-523 CASE - MECHANICAL OUTLINE

BOTTOM VIEW



**LEAD CODE:**

- 1) BASE
- 2) EMITTER
- 3) COLLECTOR

DEVICE	MARKING CODE
BC856AT	GT6
BC856BT	GT7
BC857AT	GT8
BC857BT	GT9
BC857CT	GT0

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.023	0.031	0.58	0.78
B	0.002	0.008	0.04	0.20
C	0.013	0.021	0.34	0.54
D	0.059	0.067	1.50	1.70
E	0.059	0.067	1.50	1.70
F	0.035	0.043	0.90	1.10
G	0.020		0.50	
H	0.031	0.039	0.78	0.98
J	0.010	0.014	0.25	0.35

SOT-523 (REV: R2)

This datasheet has been download from:

[www.datasheetcatalog.com](http://www.datasheetcatalog.com)

Datasheets for electronics components.